TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (MACH II π -MOS V)

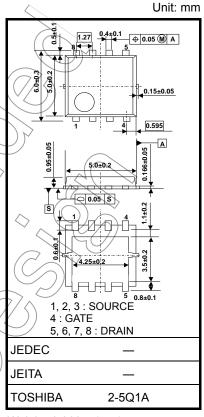
TPCA8009-H

High Speed Switching Applications Switching Regulator Applications DC/DC Converter Applications

- Small footprint due to a small and thin package
- High-speed switching
- Small gate charge: $Q_{SW} = 3.7 \text{ nC (typ.)}$
- Low drain-source ON-resistance: RDS (ON) = 0.23Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 4.5S$ (typ.)
- Low leakage current: $I_{DSS} = 100 \mu A \text{ (max) (V}_{DS} = 150 \text{ V)}$
- Enhancement mode: $V_{th} = 2.0 \text{ to } 4.0 \text{ V (VDS} = 10 \text{ V, ID} = 1 \text{ mA})$

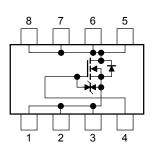
Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	150	V	
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V _{DGR}	150	V	
Gate-source voltage		V _{GSS}	±20	< <u>\</u>	
Drain current	DC (Note 1)	ID((7	A	
	Pulsed (Note 1)		14	,	
Drain power dissipation	on (Tc=25°C)	(PD \	45	/ w	
Drain power dissipation (t = 10 s) (Note 2a)		PD	2.8	W	
Drain power dissipation (t = 10 s) (Note 2b)		PD	(1.6/)	W	
Single-pulse avalanche energy (Note 3)		EAS	34	mJ	
Avalanche current		I _{AR}	7	Α	
Repetitive avalanche energy/ (Tc=25°C) (Note 4)		EAR	1.5	mJ	
Channel temperature		Tch	150	°C	
Storage temperature range		Tstg	-55 to 150	°C	



Weight: 0.068 g (typ.)

Circuit Configuration



Note: For Notes 1 to 4, refer to the next page.

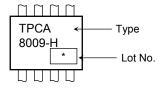
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.

Thermal Characteristics

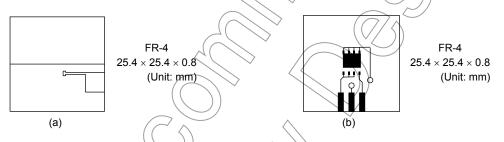
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc=25°C)	R _{th (ch-c)}	2.78	°C/W
Thermal resistance, channel to ambient $(t=10 \; s) \eqno(Note \; 2a)$	R _{th (ch-a)}	44.6	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	78.1	°C/W

Marking (Note 5)



Note 1: The channel temperature should not exceed 150°C during use.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



Note 3: $V_{DD} = 50 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (injtial), L = 1mH, $R_G = 25 \Omega$, $I_{AR} = 7 \text{ A}$

Note 4: Repetitive rating: pulse width limited by max channel temperature

Note 5: * Weekly code: (Three digits)

Week of manufacture
(01 for first week of year, continuing up to 52 or 53)

Year of manufacture

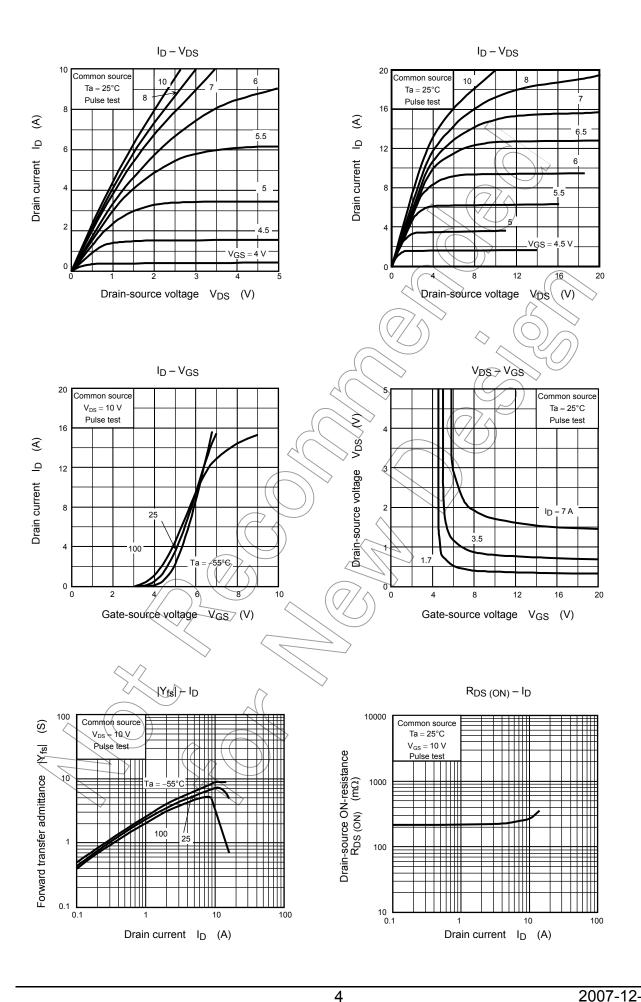
(The last digit of the calendar year)

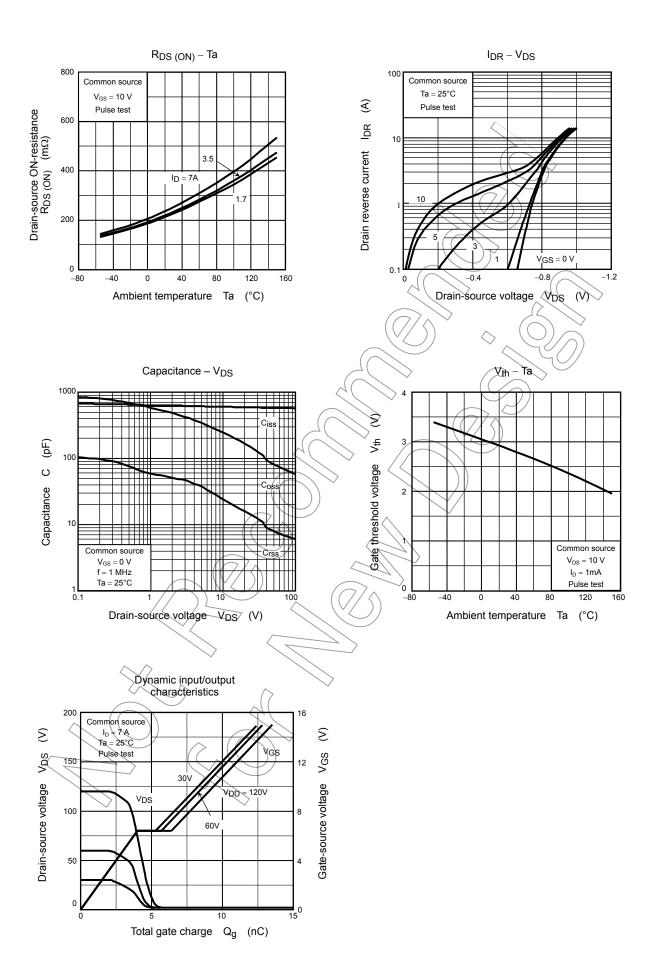
Electrical Characteristics (Ta = 25°C)

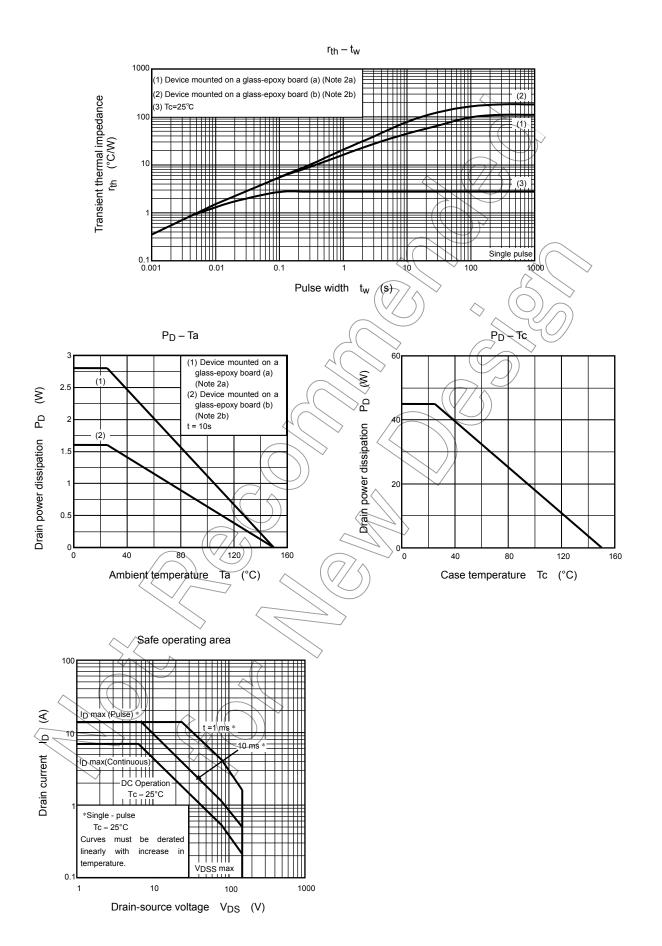
Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μΑ	
Drain cutoff curre	nt	I _{DSS}	V _{DS} = 150 V, V _{GS} = 0 V	_	_	100	μА	
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	150	_	_		
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -5 \text{ V}$	150	_	_	V	
			$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	100) >-	_		
Gate threshold vo	oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0	_	4.0	V	
Drain-source ON-	-resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 3.5 A))	0.23	0.35	Ω	
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 3.5 A	2.1	4.5	_	S	
Input capacitance)	C _{iss}		² —	600	_		
Reverse transfer capacitance		C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	20	_	pF	
Output capacitance		Coss			220	7		
Switching time	Rise time	t _r	V _{GS} 10 V ID = 3.5 A V _{OUT}			> _		
	Turn-ON time	t _{on}	G 5 \$ 2 G C C C C C C C C C C C C C C C C C C		17/	_		
	Fall time	t _f	V _{DD} ≈ 7.5 V	(\mathcal{T})	13	_	ns	
	Turn-OFF time	t _{off}	Duty ≤ 1%, t _w = 10 μs) —	70	_		
Total gate charge (gate-source plus		Qg			10	_		
Gate-source char	-ge	Qgs	$V_{DD} \simeq 120 \text{ V}, V_{GS} = 10 \text{ V},$		7.6			
Gate-drain ("miller") charge		I _D = 7 A	_	2.4		nC		
Gate switch charge				3.7				

Source-Drain Ratings and Characteristics (7a = 25°C)

Characteristic	Symbol Test Conc	lition Min	Тур.	Max	Unit
Drain reverse current Pulse (Note 1)	I _{DRP} —	_	_	14	Α
Forward voltage (diode)	V_{DSF} $V_{DR} = 7 A$, $V_{GS} = 0 V$	_	_	-2.0	V







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